

View Online at <https://aerobasegroup.com/nsn/5961-01-619-1809>

**End Application:**

C130 acft

**Semiconductor Material:**

Silicon

**Voltage Rating In Volts Per Characteristic:**

110.0 collector to base voltage, dc and 110.0 collector to emitter voltage, dc and 55.0 collector to emitter voltage, dc and 4.0 emitter to base voltage, dc

**Current Rating Per Characteristic:**

20.0 amperes collector current, dc

**Power Rating Per Characteristic:**

320.0 watts total device dissipation

**Special Features:**

Description: set of eight 150w pep, 2-30mhz transistors; unit of measure: matched octal; 150 watt (w) npn silicon radio frequency (rf) power transistor for use in high frequency (hf) broadband linear power amplifiers from 20 to 30mhz

**Shelf Life:**

N/a

**Unit Of Measure:**

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**Demilitarization:**

No

**Fiig:**

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